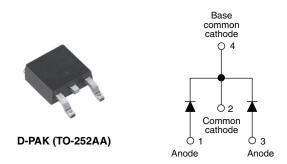
Vishay Semiconductors



High Performance Schottky Rectifier, 2 x 3.5 A



PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 3.5 A						
V _R	100 V						
V _F at I _F	See Electrical table						
I _{RM}	4.9 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	5 mJ						

FEATURES

- Popular D-PAK outline
- Center tap configuration
- · Small foot print, surface mountable
- · Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-6CWQ10FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	7	А						
V _{RRM}		100	V						
I _{FSM}	$t_p = 5 \ \mu s \ sine$	440	А						
V _F	3 A _{pk} , T _J = 125 °C (per leg)	0.63	V						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6CWQ10FNPbF	UNITS						
Maximum DC reverse voltage	V _R	100	V						
Maximum working peak reverse voltage	V _{RWM}	100	v						

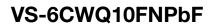
ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS						
Maximum average per	<i>с</i> .	50 % duty cycle at T_{C} = 135 °C, r	3.5						
See fig. 5 per dev	Ce I _{F(AV)}	50% duty cycle at $T_{\rm C} = 135$ C, T	7	А					
Maximum peak one cycle non-repetitive surge current per leg		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	440	A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	70					
Non-repetitive avalanche energy per le	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 10 mH		5.0	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А				

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		3 A	T.I = 25 °C	0.81				
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	6 A	1j=23 0	0.96	V			
See fig. 1	VFM ()	3 A	T 105 %C	0.63				
		6 A	T _J = 125 °C	0.74				
Maximum reverse	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	1	mA			
leakage current per leg See fig. 2		T _J = 125 °C	V _R = nated V _R	4.9	ША			
Threshold voltage	V _{F(TO)}	T T maximum	T _J = T _J maximum -		V			
Forward slope resistance	r _t	$I_{J} = I_{J} maximum$			mΩ			
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$, (test signal ran	92	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 m	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

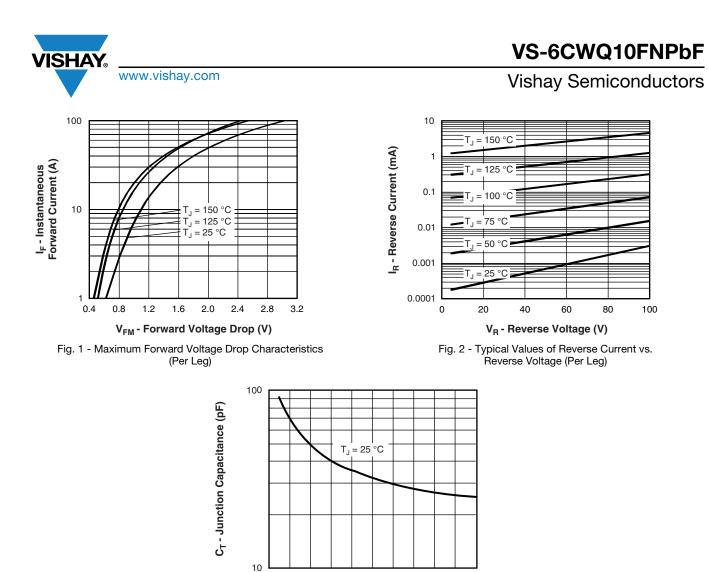
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance,	per leg	P	DC operation	4.70	°C/W				
junction to case	per device	R _{thJC}	See fig. 4	2.35					
Approximate weight				0.3	g				
				0.01	oz.				
Marking device			Case style D-PAK (similar to TO-252AA)	6CWQ10FN					

Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



V_R - Reverse Voltage (V)

60

80

100

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

40

20

0

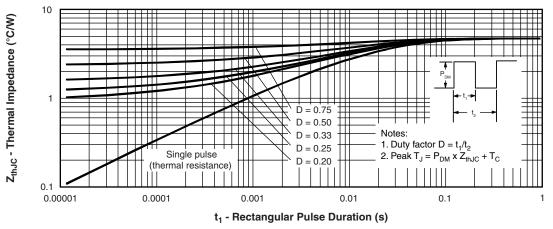
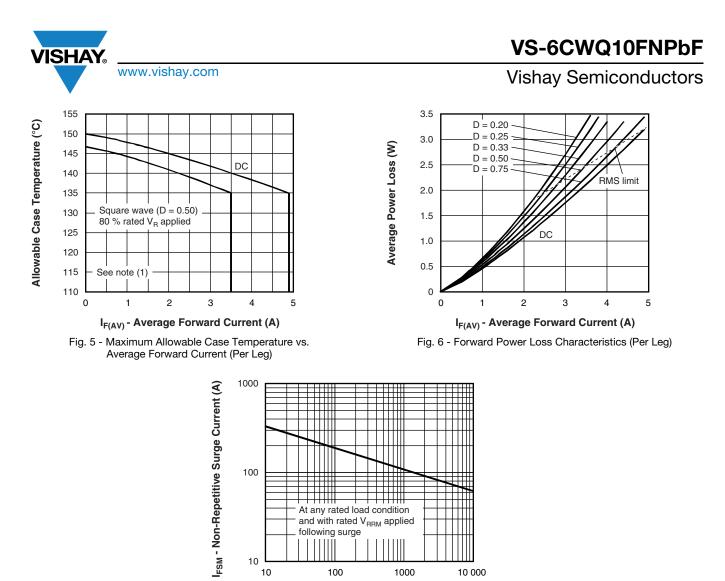


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

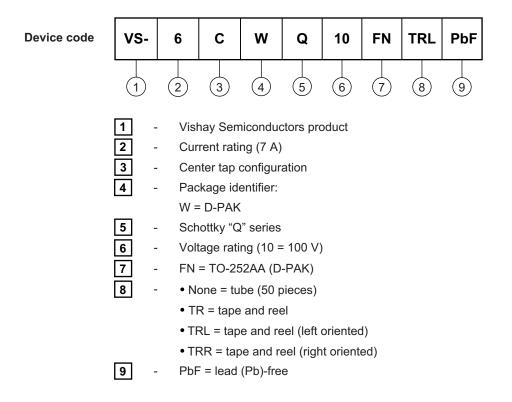
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ORDERING INFORMATION TABLE

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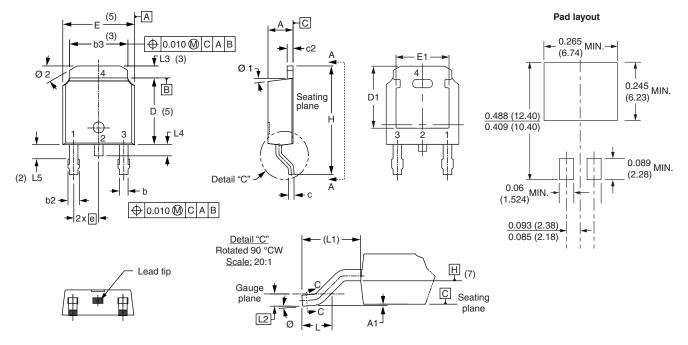
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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